NSN 5961-00-862-7482

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-00-862-7482

Inclosure Material:

Metal

Overall Length:

1.005 inches

Overall Height:

Between 0.240 inches and 0.260 inches

Overall Width:

Between 0.495 inches and 0.505 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

450.0 breakdown voltage, collector-to-base, emitter open and 450.0 breakdown voltage, collector-to-emitter, base open and 7.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 500.00 milliamperes source cutoff current and 1.00 amperes source cutoff current

Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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